

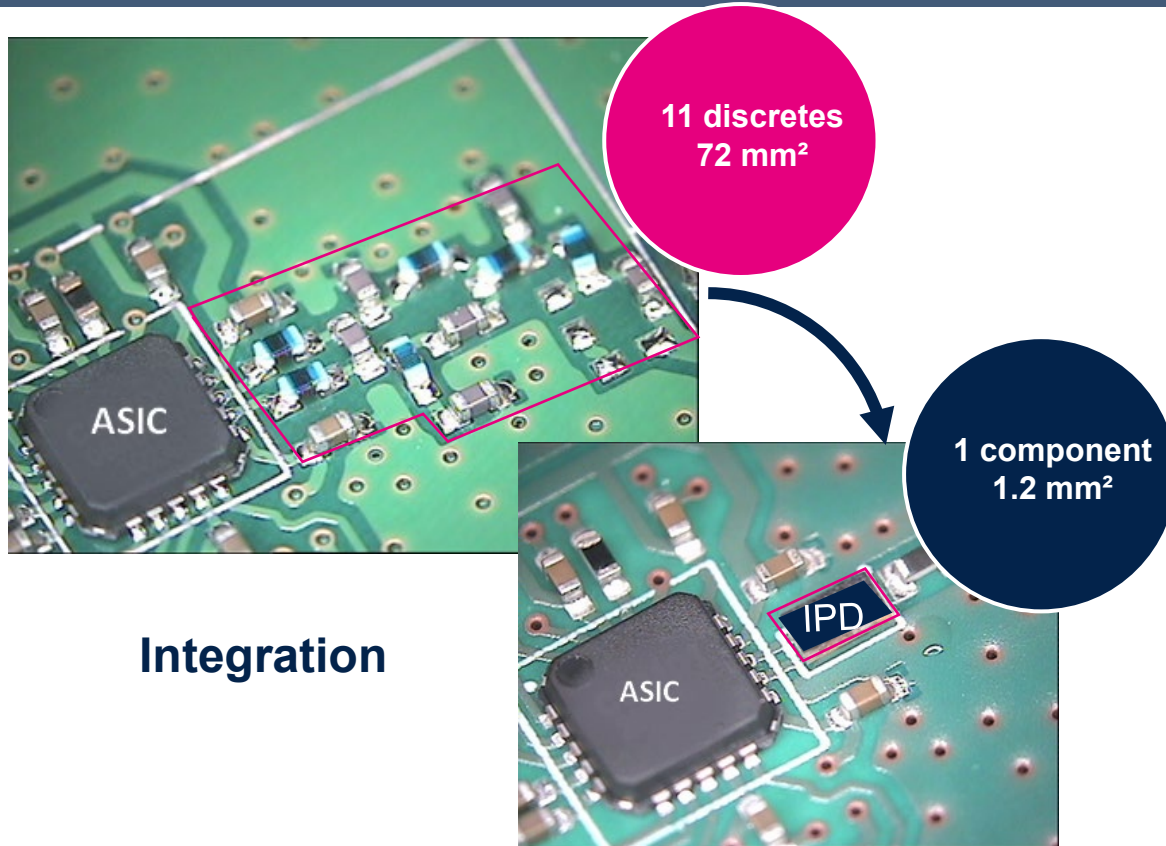


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Integrated passive devices (IPD) for RF applications

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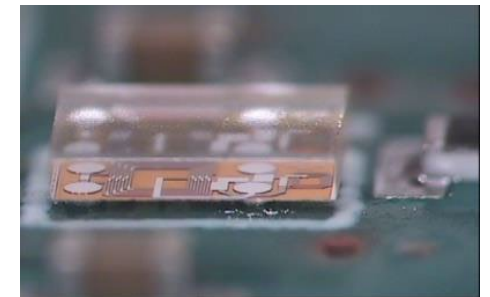
ST integrated passive devices offer a competitive cost structure, a small form factor, and reduced power losses



Covering all RF applications with a frequency range from 168 MHz and above including Sub-1 GHz, WLAN, Bluetooth, ZigBee, WiMax, UWB, UMTS, LTE, and more.

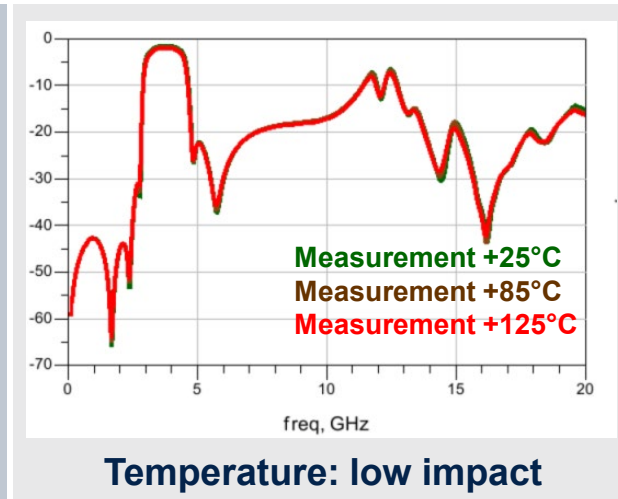
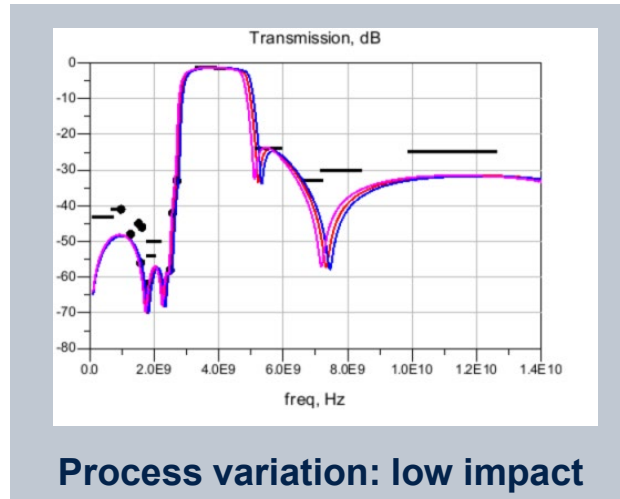
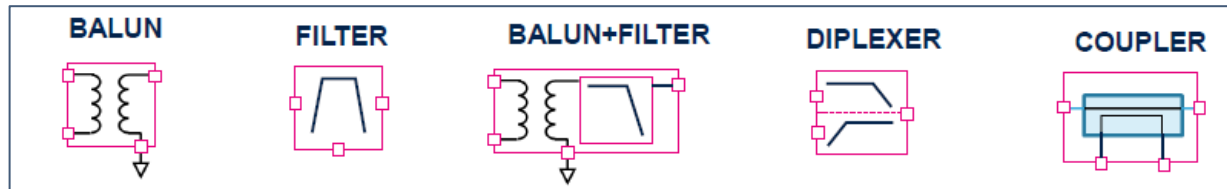
Summary of key benefits

- Design **simplification**
- Same **performance** across components, tolerances, and temperature
- System **integration**
- **Reliability** improvement
- BOM **reduction**
- Successful **development** story



What are RF integrated passive devices?

The technology is dedicated to design RF products on glass or high resistivity substrate

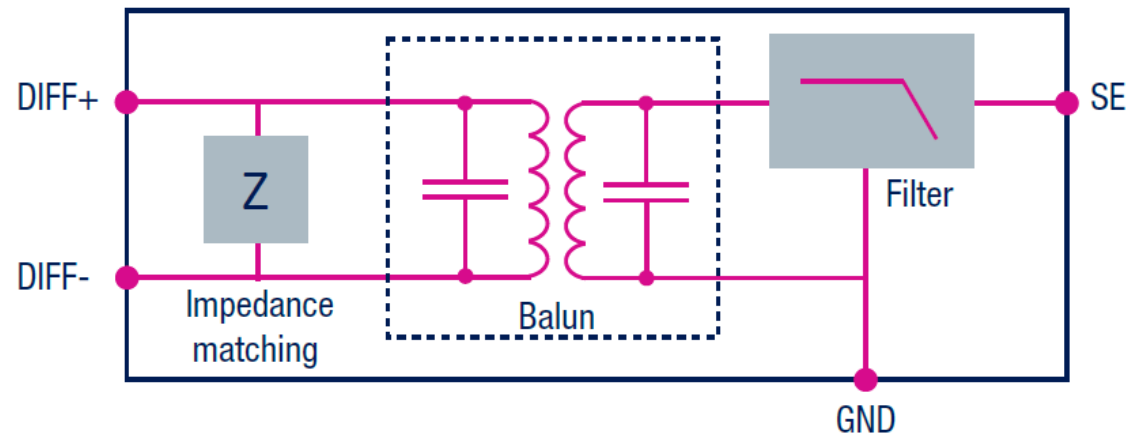


- Design simplification & performance optimization
- System integration & reliability improvement
- BOM reduction
- Easier and successful development process
- Lower thickness than LTCC
- Low process variation versus discrete/LTCC
- Low temperature impact versus discrete/LTCC

Tuned for high RF integration

ST RF IPD baluns improve system performance & simplify RFIC to antenna matching network complexity

Designed with integrated harmonic filters, they facilitate compliance with major EMC regulations: CCC, FCC, ETSI, ARIB



ST baluns integrate the following functions:

- Impedance matching
- 50 Ω nominal input impedance
- Harmonic filter

IPD benefits versus LTCC

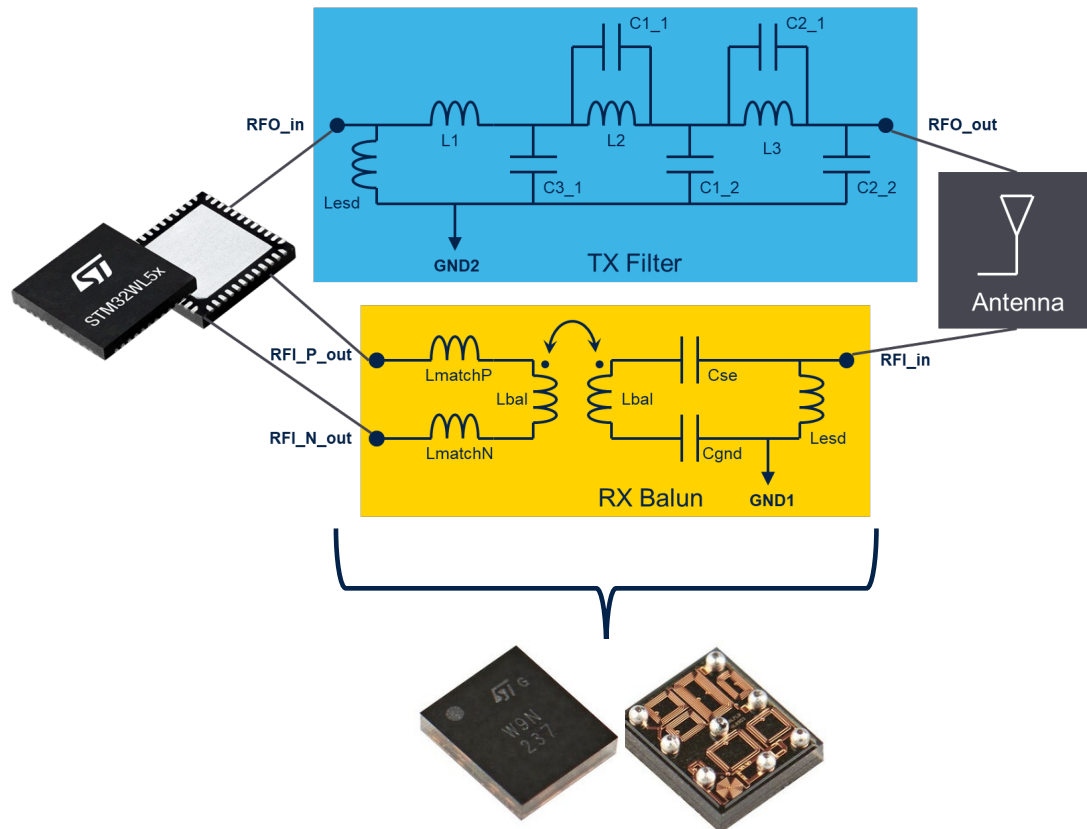
	IPD	LTCC	Discretes
Thickness	Very good	Good	Medium
Integration	Very good	Good	Bad
Flexibility	Very good	Low	Very good
Complexity simplification	Very good	Good	Low
Space/area	Good	Medium	Bad
Performances (losses, etc.)	Very good	Good	Low
Standardness	Medium	Very good	Very good
Integrated matching	Very good	Good	Low
Summary	★ ★ ★	★ ★	★

**RF IPD products for STM32WL5, STM32WL3,
SPIRIT1, and S2-LP long rang wireless ICs**



RF IPD companion chips for STM32WL5

IPD die replaces 14 discrete L&C components and one balun



- 9 IPD products
 - Developed to match each STM32WL configuration
 - Pin to pin compatible
- IPD die contain:
 - Tx matching networks
 - Rx matching networks
 - Balun
 - Harmonics filter
 - ESD shunt inductor

RF IPD companion chips for STM32WL5

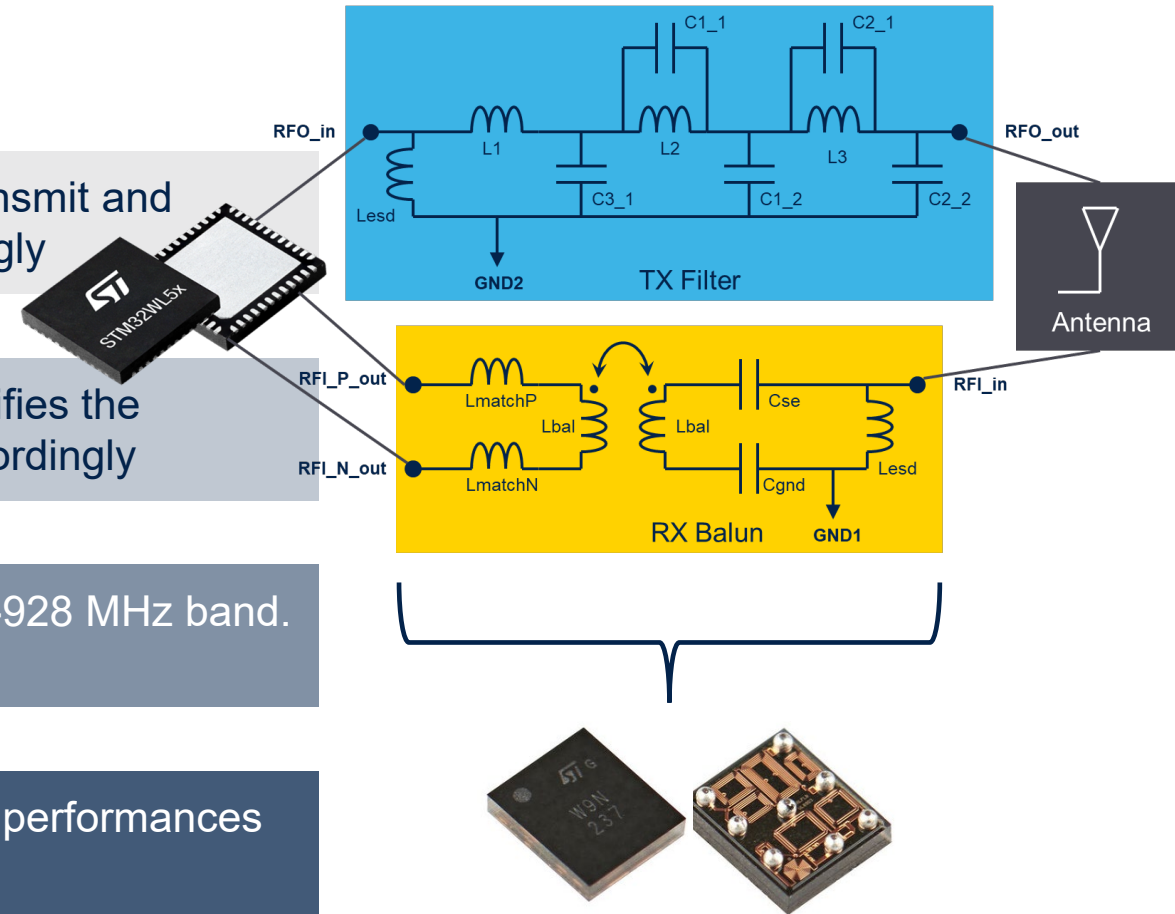
The reason for 9 products

STM32WL package: the STM32WL package has an impact on the transmit and receive impedances. L&C values in IPD die must be modified accordingly

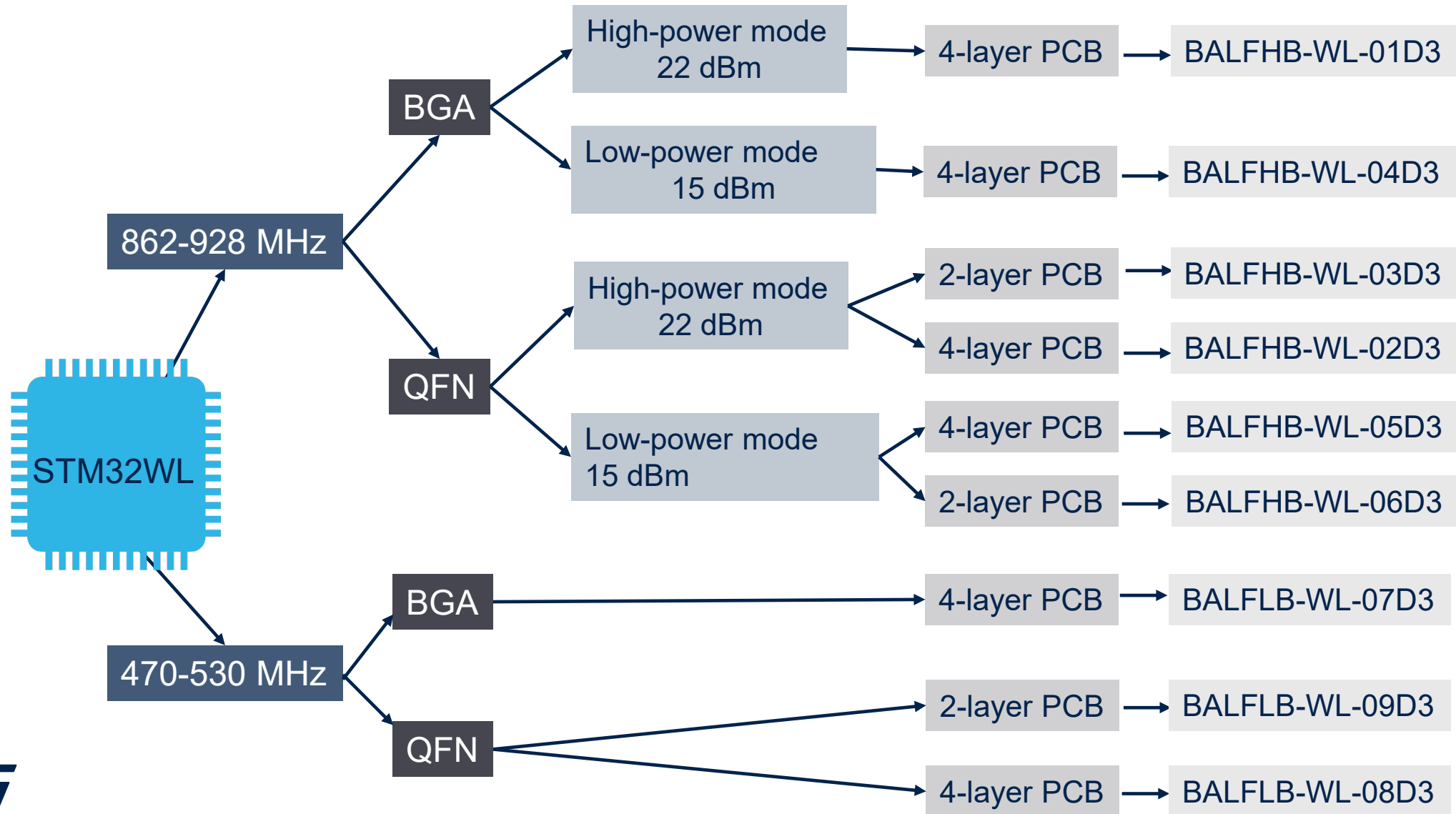
STM32WL power level: increasing or decreasing the power level modifies the impedance of STM32WL. L&C values in IPD die must be modified accordingly

Frequency band: STM32WL can work at 470-530 MHz band and 862-928 MHz band. Different products for each band

Customer PCB (number of layers): the number of layers impacts RF performances and impedance levels



Choosing the RF IPD companion chip for STM32WL5



Choosing the RF IPD companion chip for STM32WL5

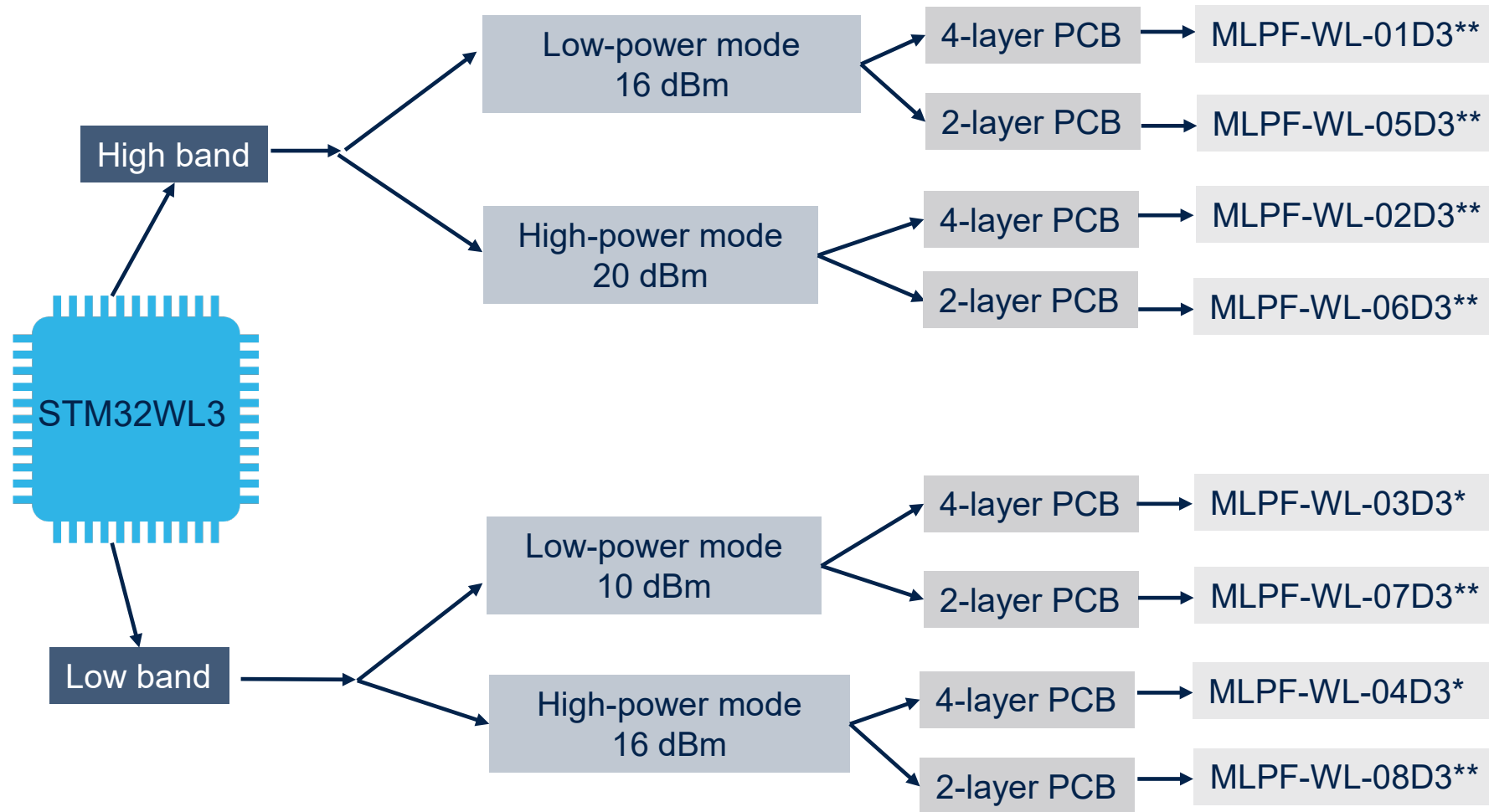
All the products are qualified EPL and are part of the ST 10-year longevity program

Power frequency	High power mode 862-928 MHz		Low power mode 862-928 MHz	
# PCB layers	4 layers	2 layers	4 layers	2 layers
STM32WL5 high band BGA	BALFHB-WL-01D3		BALFHB-WL-04D3	
STM32WL5 high band QFN	BALFHB-WL-02D3	BALFHB-WL-03D3	BALFHB-WL-05D3	BALFHB-WL-06D3
power frequency	High power mode 470-510 MHz			
# PCB layers	4 layers	2 layers		
STM32WL5 low band BGA	BALFHB-WL-07D3			
STM32WL5 low band QFN	BALFHB-WL-08D3	BALFHB-WL-09D3		

1. 868, 915, and 490 MHz most common frequencies
2. 15, 17, or 22 dBm power level
3. BGA or QFN package
4. 2- or 4-layer PCB

RF IPDs products companion chip to STM32WL3

how to pick up the right one



* Qualification Q2 2024

** Qualification Q4 2024

Choosing the RF IPD companion chip for SPIRIT1 and S2-LP

All the products are qualified EPL and are part of the ST 10-year longevity program

	High-power mode High-frequency band		Low-power mode Low-frequency band	
	4 layers	2 layers	4 layers	2 layers
SPIRIT1	BALF-SPI-01D3		BALF-SPI-02D3	
S2-LP	BALF-SPI2-01D3	BALF-SPI2-03D3*	BALF-SPI2-02D3	

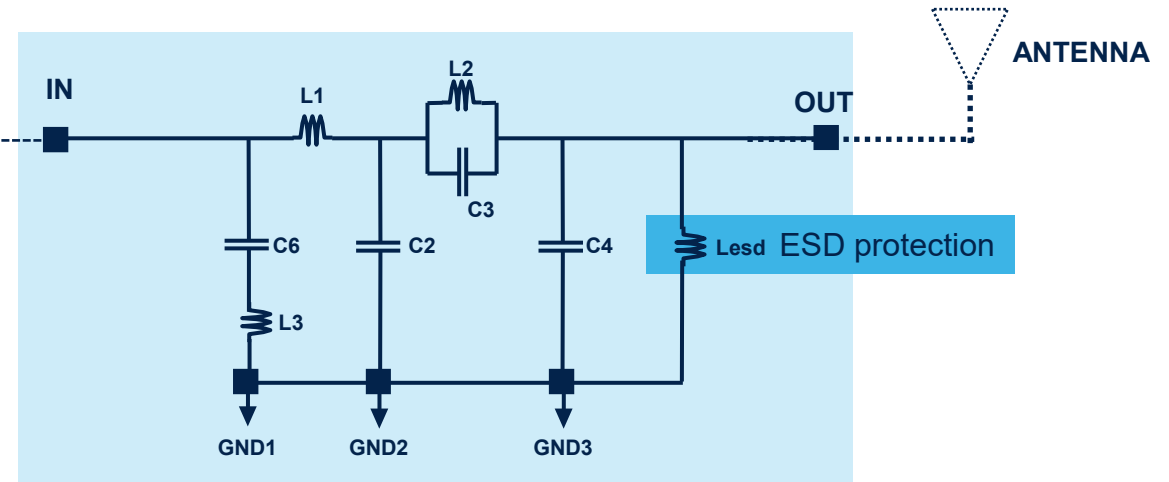
1. 868, 915, 433, or 490 MHz most common frequencies
2. 14 or 16 dBm power level
3. 2- or 4-layer PCB

RF IPD products for STM32WB and BlueNRG Bluetooth® Low Energy chips

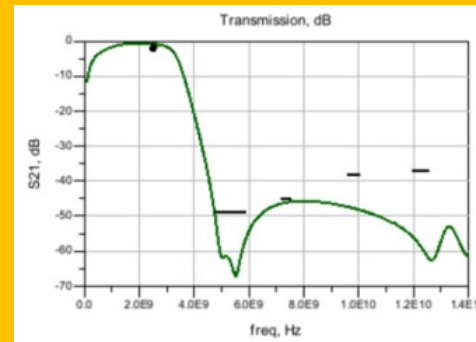
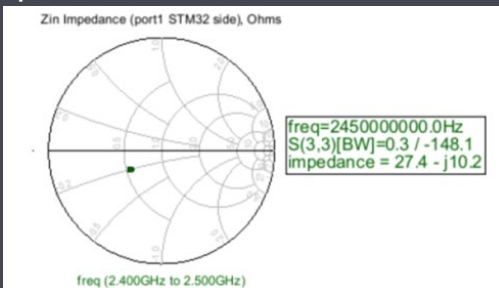


RF IPD companion chip to STM32WB

Harmonics filtering, impedance matching, and ESD protection in one die

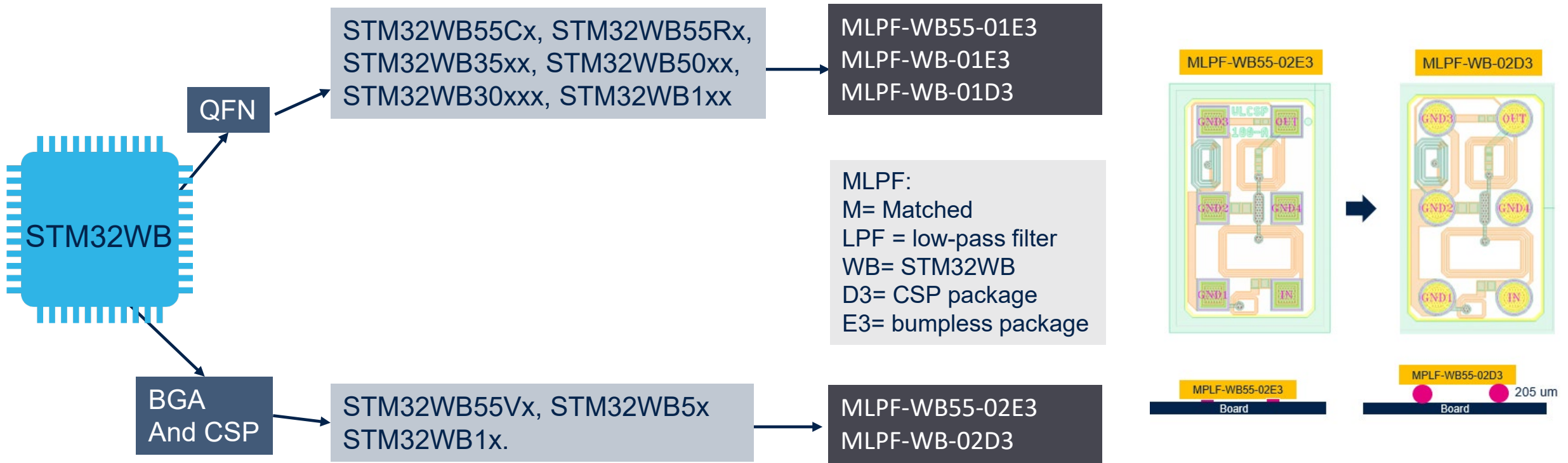


Direct match of STM32WB impedance



Deep attenuation to answer system requirements

RF IPD companion chip to STM32WB 5 Products

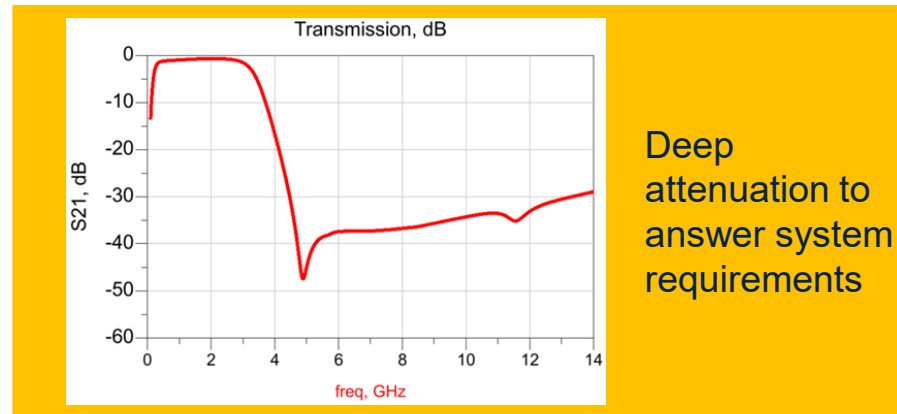
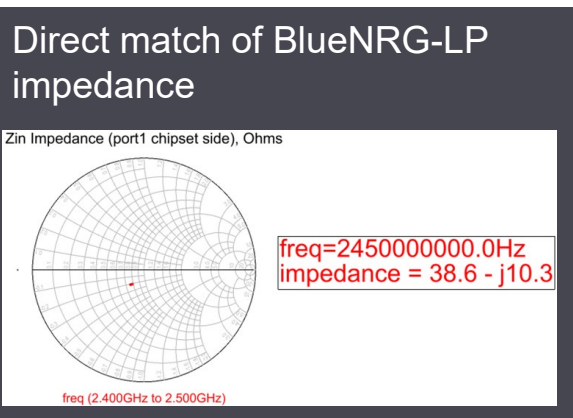
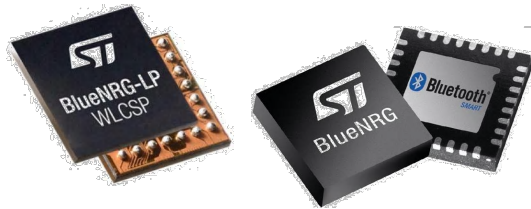
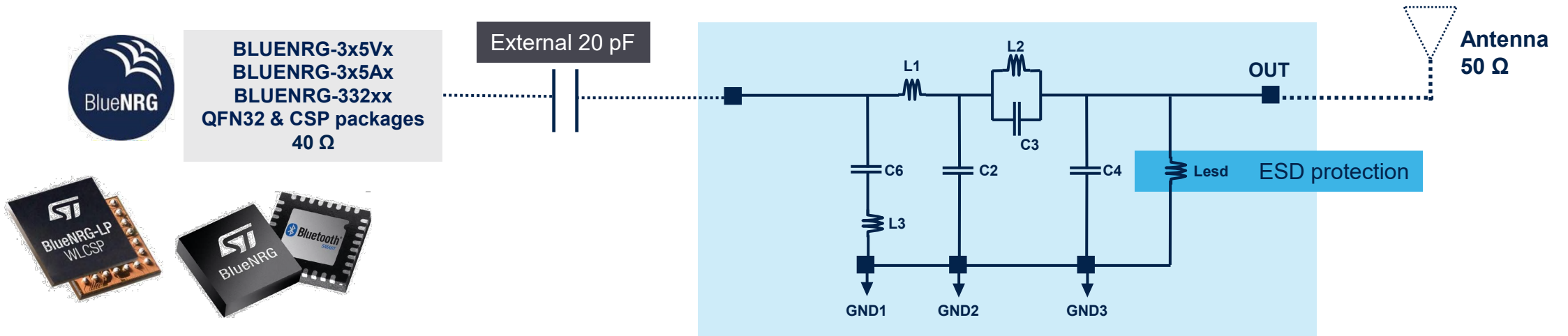


RF IPD companion chips for STM32WB

STM32 part number	STM32 package	RF IPD part number
STM32WB55Cx, STM32WB55Rx, STM32WB35xx, STM32WB50xx, STM32WB30xxx, STM32WB1xx	QFN	MLPF-WB-01D3
STM32WB55Cx, STM32WB55Rx, STM32WB35xx, STM32WB50xx, STM32WB30xxx, STM32WB1xx	QFN	MLPF-WB-01E3
STM32WB55Cx, STM32WB55Rx, STM32WB35xx, STM32WB50xx, STM32WB30xxx, STM32WB1xx	QFN	MLPF-WB55-01E3
STM32WB5x and STM32WB1x, STM32WB55Vx	BGA/CSP	MLPF-WB-02D3
STM32WB5x and STM32WB1x, STM32WB55Vx	BGA/CSP	MLPF-WB55-02E3

RF IPD companion chip for BlueNRG LP/LPS

Harmonics filtering, impedance matching, and ESD protection in one die



MLPF-NRG-01D3 RF IPD companion chip for BlueNRG-LP/LPS

One product compatible with all the following ICs

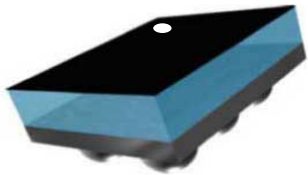
IC	Package	Part number
BLUERNG-LP	QFN32	BLUENRG-345AC BLUENRG-355AC BLUENRG-345AT BLUENRG-355AT
	QFN48	BLUENRG-345MC BLUENRG-355MC BLUENRG-345MT BLUENRG-355MT
	WLCSP	BLUENRG-345VC BLUENRG-355VC BLUENRG-345VT BLUENRG-355VT
BLUENRG-LPS	QFN32	BLUENRG-332AC BLUENRG-332AT
	WLCSP	BLUENRG-332VT

MLPF-WB-04D3 RF IPD companion chip for STM32WBA

Harmonics filtering, impedance matching, and ESD protection in one die

- Designed to simplify the RF path between STM32WBA and antenna
- Optimizes performance, BOM, and reliability
- System integration: small die size 1.6 x 1 mm²

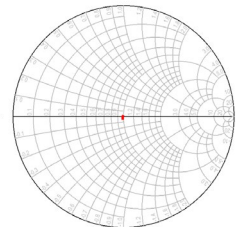
MLPF-WB-04D3 1.6 x 1 mm²



Chip scale package on glass 6 bumps

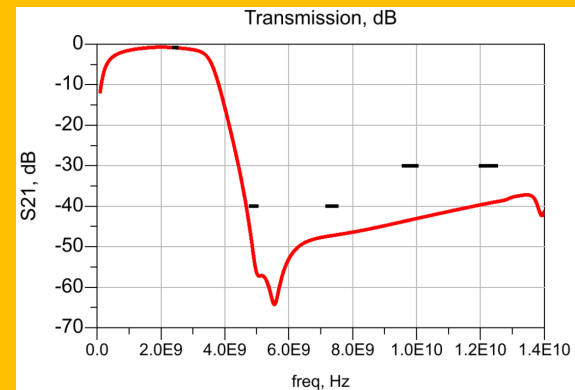
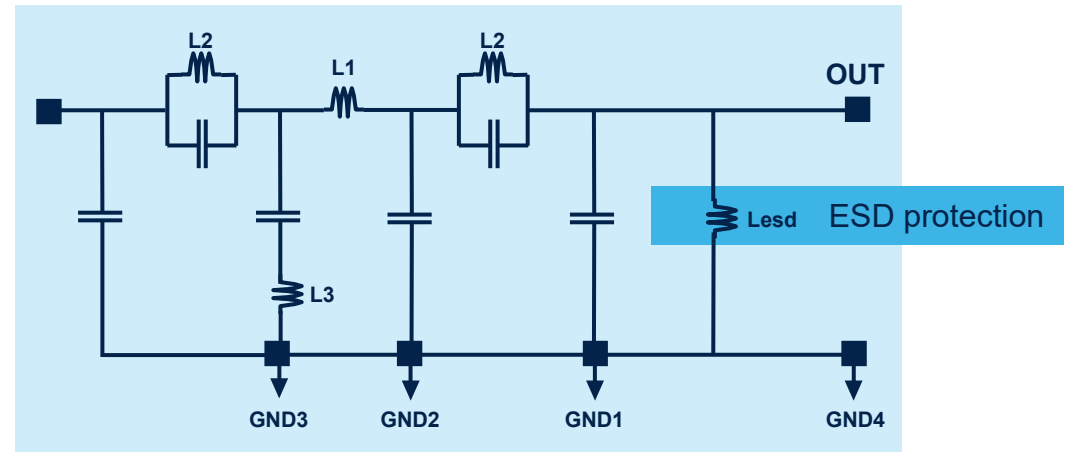
Direct match of STM32WBA impedance

Zin Impedance (port1 STM32 side), Ohms



freq=2440000000.0Hz
impedance = 49.3 - j0.9

freq (2.400GHz to 2.500GHz)



Deep attenuation to answer system requirements

Our technology starts with You



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